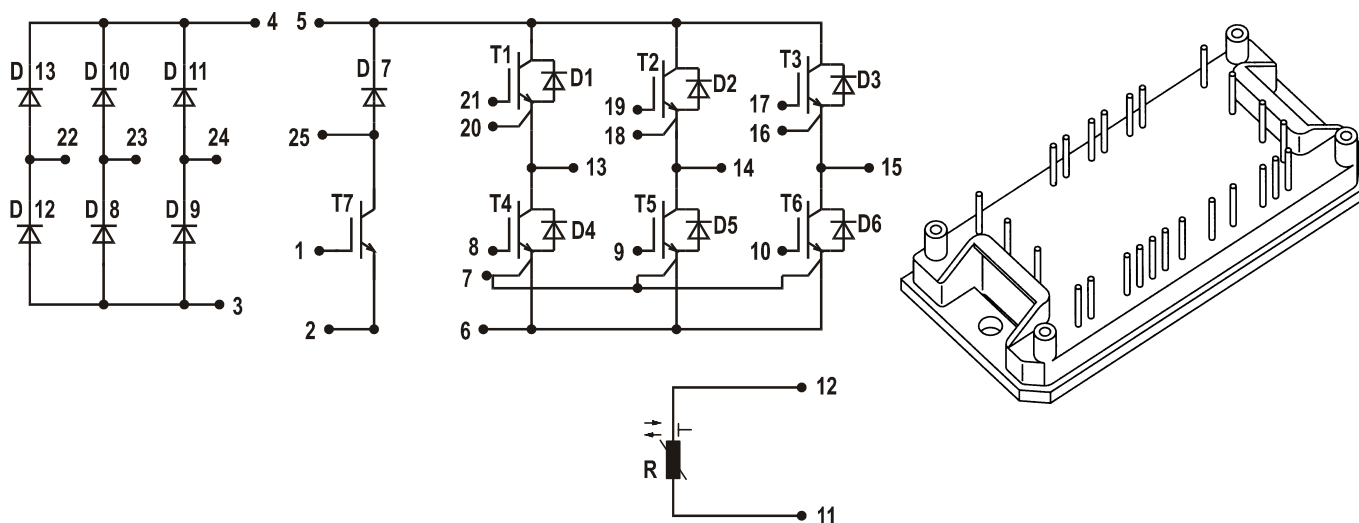


Converter - Brake - Inverter Module (CBI1)



Rectifier	Brake	Inverter
$V_{RRM} = 1200V$	$V_{CES} = 600V$	$V_{CES} = 600V$
$I_{FAVM} = 25A$	$I_{C25} = 23A$	$I_{C25} = 38A$
$I_{FSM} = 370A$	$V_{CE(sat)} = 2.1V$	$V_{CE(sat)} = 2.1V$

Input Rectifier Bridge D8 - D13

Symbol	Conditions	Maximum Ratings	
V_{RRM}		1200	V
I_F	$T_{VJ} = 25^{\circ}C$	55	A
I_{FAVM}	$T_{VJ} = 150^{\circ}C$; $T_K = 70^{\circ}C$	25	A
I_{FSM}	$T_{VJ} = 45^{\circ}C$; $t = 10\text{ ms sine } 50\text{ Hz}$	370	A
i^2t	$T_{VJ} = 125^{\circ}C$	680	A ² s
T_{VJ}		+150	$^{\circ}C$

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}C$, unless otherwise specified)		
		min.	typ.	max.
I_R	$V_{RRM} = 1200V$; $T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$			20 μA 2 mA
V_F	$I_F = 55A$		1.2	1.46 V
R_{thJC}	per die		1.05	$^{\circ}C/W$

Features

- NPT IGBT technology
Square RBSOA, no latchup
- Free wheeling diodes with Hiperfast and soft recovery behaviour
- Isolation voltage 2500 V~
- Built in temperature sense
- High level of integration:
one module for complete drive system
- Direct Copper Bonded Al_2O_3 ceramic base plate

Applications

- AC motor control
- AC servo and robot drives

Advantages

- No need of external isolation
- Easy to mount with two screws
- Package designed for wave soldering
- High temperature and power cycling capability

IXYS reserves the right to change limits, test conditions and dimensions.

Output Inverter T1 - T6, D1 - D6

Symbol	Conditions	Maximum Ratings	
V_{CES}	$T_{VJ} = 25^{\circ}\text{C}$	600	V
V_{CGR}	$T_{VJ} = 25^{\circ}\text{C}; R_{GE} = 20\text{k}\Omega$	600	V
V_{GE}	$T_{VJ} = 25^{\circ}\text{C}$	± 20	V
I_C	$T_C = 25^{\circ}\text{C}$	38	A
	$T_C = 90^{\circ}\text{C}$	22	A
I_{CM}	$t_p = 1\text{ ms} = 1\% \text{ duty cycle}; T_C = 25^{\circ}\text{C}$ $T_C = 90^{\circ}\text{C}$	76	A
		44	A
t_{SC}	IGBT $V_{CE} = 600\text{ V}; T_{VJ} = 125^{\circ}\text{C}$ non-repetitive	10	μs
P_{tot}	$T_C = 25^{\circ}\text{C}$	104	W
T_{VJ}	Free-Wheeling Diode	+150	$^{\circ}\text{C}$
T_{VJ}	IGBT	+150	$^{\circ}\text{C}$

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)		
		min.	typ.	max.
I_{CES}	$V_{GE} = 0\text{ V}; V_{CE} = 600\text{ V}$			1 mA
I_{GES}	$V_{CE} = 0\text{ V}; V_{GE} = 25\text{ V}$			100 nA
$V_{GE(th)}$	$V_{GE} = V_{CE}; I_C = 0.7\text{ mA}$	4.5	5.5	6.5 V
$V_{(BR)CES}$	$V_{GE} = 0\text{ V}; I_C = 10\text{ mA}; T_{VJ} = -40^{\circ}\text{C}$	600		V
V_{CEsat}	$V_{GE} = 15\text{ V}; I_C = 30\text{ A}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2.1	2.5 V
			2.4	2.8 V
t_f	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CC} = 300\text{ V}; I_C = 30\text{ A}$ $R_G = 33\ \Omega; V_{GE} = \pm 15\text{ V}$		30	ns
t_r			35	ns
$t_{d(on)}$			30	ns
$t_{d(off)}$			190	ns
E_{off}			0.8	mJ
E_{on}			1.15	mJ
C_{iss}	$V_{GE} = 0\text{ V}$ $V_{CE} = 25\text{ V}$ $f = 1\text{ MHz}$		1600	pF
C_{oss}			170	pF
C_{rss}			100	pF
g_{fs}	$V_{CE} = 20\text{ V}; I_C = 30\text{ A}$	8		S
Q_g	$V_{CC} = 300\text{ V}; I_C = 30\text{ A pulse}; V_{GE} = 15\text{ V}$		92	nC
V_F	$I_F = 30\text{ A}; V_{GE} = 0\text{ V}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2	V
			1.8	V
t_{rr}	$I_F = 30\text{ A}; V_{GE} = 0\text{ V}; T_{VJ} = 125^{\circ}\text{C}$ $V_R = -300\text{ V}; di_F/dt = -800\text{ A}/\mu\text{s}$		0.3	μs
Q_r	$I_F = 30\text{ A}; V_R = -300\text{ V}; T_{VJ} = 25^{\circ}\text{C}$ $di_F/dt = -800\text{ A}/\mu\text{s}; V_{GE} = 0\text{ V}; T_{VJ} = 125^{\circ}\text{C}$		1.8	μC
			3.8	μC
I_r				250 μA
R_{thJC}	IGBT (per die)		1.0	$^{\circ}\text{C}/\text{W}$
	Diode (per die)		1.3	$^{\circ}\text{C}/\text{W}$

Brake Chopper T7, D7

Symbol	Conditions	Maximum Ratings	
V _{CES}	T _{VJ} = 25°C	600	V
V _{CGR}	T _{VJ} = 25°C; R _{GE} = 20kΩ	600	V
V _{GE}	T _{VJ} = 25°C	±20	V
I _C	T _C = 25°C	23	A
	T _C = 90°C	13	A
I _{CM}	t _p = 1 ms = 1% duty cycle; T _C = 25°C 		

Symbol	Conditions	Characteristic Values ($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)		
		min.	typ.	max.
I_{CES}	$V_{GE} = 0\text{ V}; V_{CE} = 600\text{ V}$			1 mA
I_{GES}	$V_{CE} = 0\text{ V}; V_{GE} = 25\text{ V}$			100 nA
$V_{GE(th)}$	$V_{GE} = V_{CE}; I_C = 0.4\text{ mA}$	4.5	5.5	6.5 V
$V_{(BR)CES}$	$V_{GE} = 0\text{ V}; I_C = 10\text{ mA}; T_{VJ} = -40^{\circ}\text{C}$	600		V
$V_{CE(sat)}$	$V_{GE} = 15\text{ V}; I_C = 15\text{ A}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2.1	2.5 V
			2.4	2.8 V
t_f	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CC} = 300\text{ V}; I_C = 15\text{ A}$ $R_G = 68\text{ }\Omega; V_{GE} = \pm 15\text{ V}$		25	ns
t_r			25	ns
$t_{d(on)}$			30	ns
$t_{d(off)}$			200	ns
E_{off}			0.5	mJ
E_{on}			0.7	mJ
C_{iss}	$V_{GE} = 0\text{ V}$ $V_{CE} = 25\text{ V}$ $f = 1\text{ MHz}$		800	pF
C_{oss}			85	pF
C_{rss}			52	pF
g_{fs}	$V_{CE} = 20\text{ V}; I_C = 15\text{ A}$	4.5		S
Q_g	$V_{CC} = 300\text{ V}; I_C = 15\text{ A pulse}; V_{GE} = 15\text{ V}$		59	nC
V_F	$I_F = 15\text{ A}; V_{GE} = 0\text{ V}; T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2	V
			1.8	V
t_{rr}	$I_F = 15\text{ A}; V_R = -300\text{ V}; T_{VJ} = 125^{\circ}\text{C}$ $di_F/dt = -500\text{ A}/\mu\text{s}; V_{GE} = 0\text{ V}$		0.25	μs
Q_r	$I_F = 15\text{ A}; V_R = -300\text{ V}; T_{VJ} = 25^{\circ}\text{C}$ $di_F/dt = -500\text{ A}/\mu\text{s}; V_{GE} = 0\text{ V}; T_{VJ} = 125^{\circ}\text{C}$		0.4	μC
			1.3	μC
I_r				250 μA
R_{thJC}	IGBT (per die)		1.5	$^{\circ}\text{C}/\text{W}$
	Diode (per die)		2.0	$^{\circ}\text{C}/\text{W}$

Module

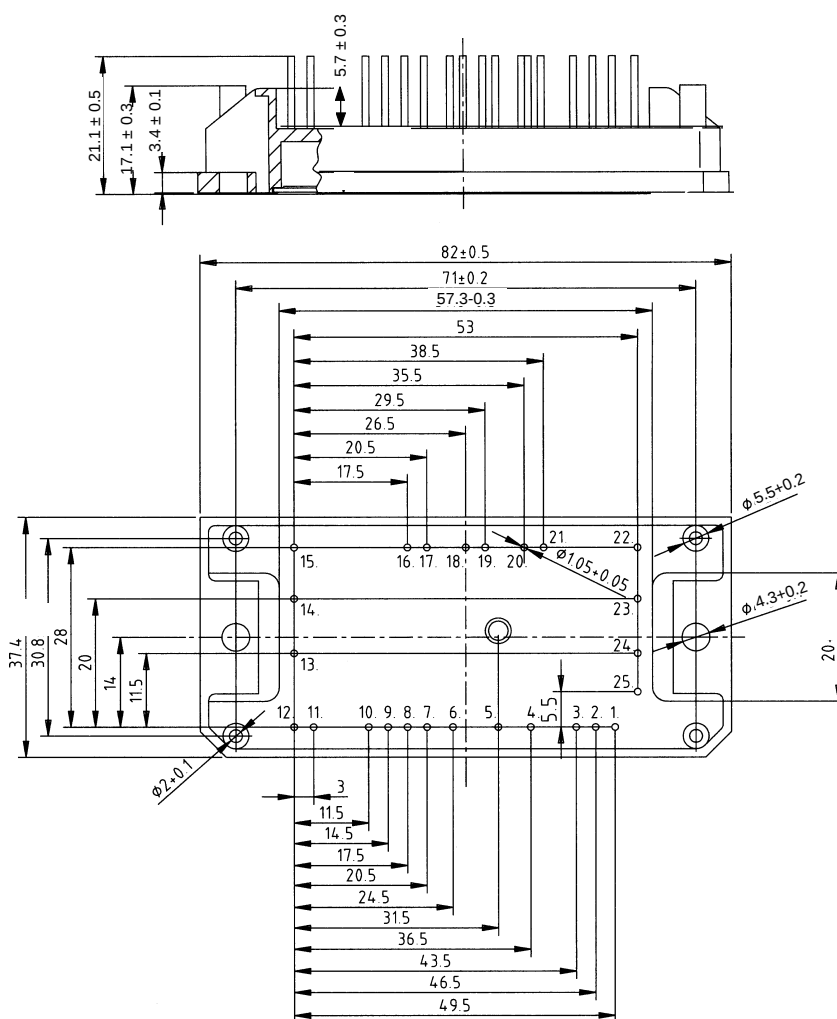
Symbol	Conditions	Maximum Ratings	
T_{stg}		-40...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1 \text{ mA}$; 50/60 Hz; $t = 1 \text{ min}$	2500	V~
M_d	Mounting torque (M4)	2.0 - 2.2 18 - 20	Nm lb.in.
d_s	Creepage distance on surface	12.7	mm
d_A	Strike distance in air	12.7	mm
Weight	typ.	42	g

Temperature Sensor R

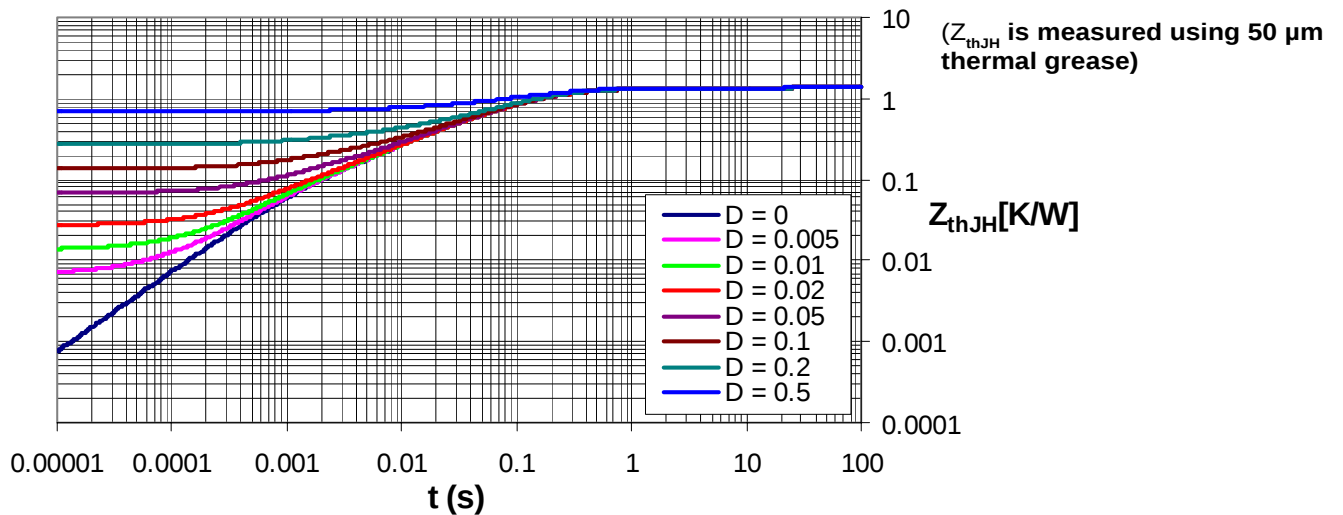
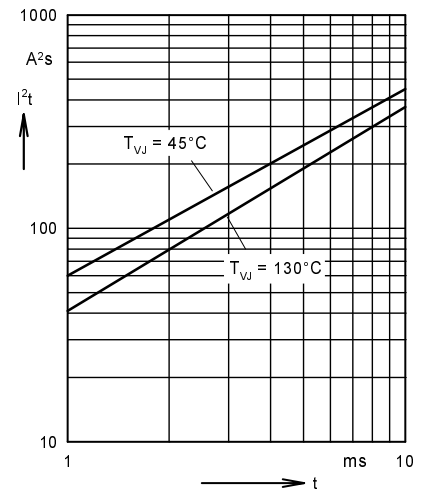
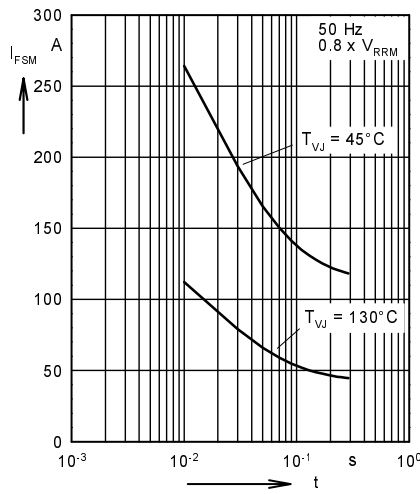
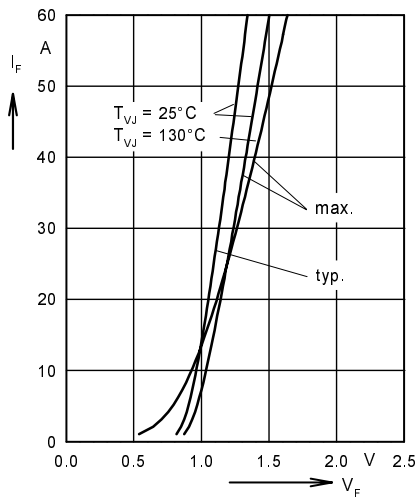
Symbol	Conditions	Maximum Ratings	
R	$T_{amb} = 20^\circ\text{C}$	4.7	k Ω

For additional data see C620/4.7k 5% S+M NTC thermistor catalog

Dimensions in mm (1 mm = 0.0394")



Input Rectifier Bridge D8 - D13

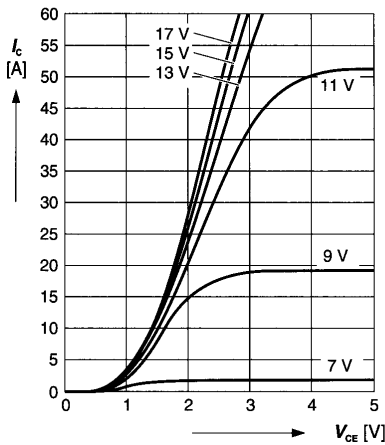


Output Inverter T1 - T6

Typ. output characteristics

$$I_C = f(V_{CE})$$

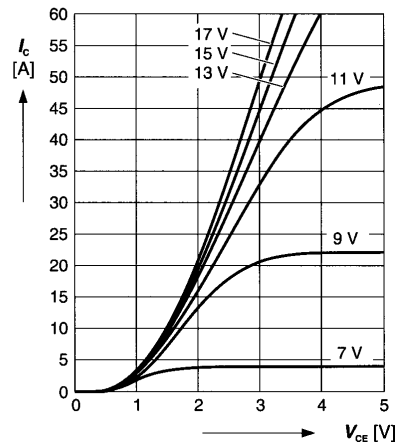
parameter: $t_p = 250 \mu s$; $T_j = 25^\circ C$



Typ. output characteristics

$$I_C = f(V_{CE})$$

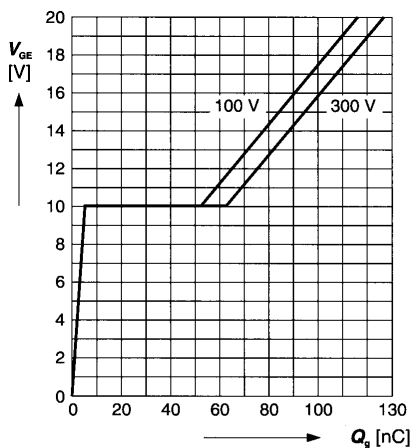
parameter: $t_p = 250 \mu s$; $T_j = 125^\circ C$



Typ. gate charge

$$V_{GE} = f(Q_g)$$

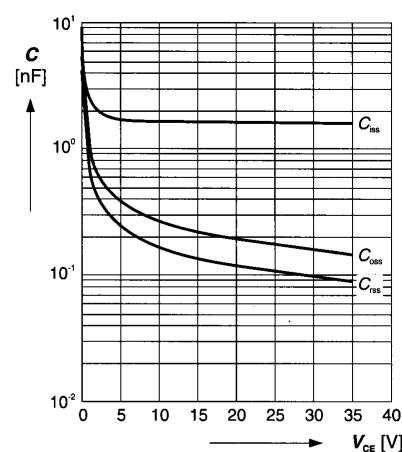
parameter: $I_{C\text{ puls}} = 30 A$



Typ. capacitances

$$C = f(V_{CE})$$

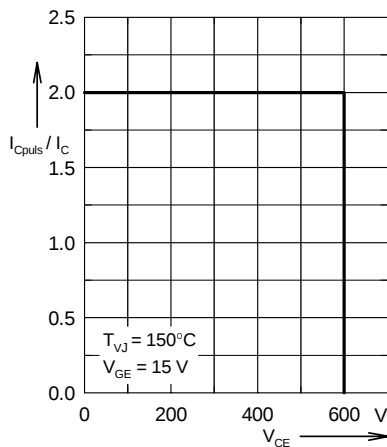
parameter: $V_{GE} = 0 V$; $f = 1 MHz$



Reverse biased safe operating area

$$I_{C\text{ puls}} = f(V_{CE}), T_j = 150^\circ C$$

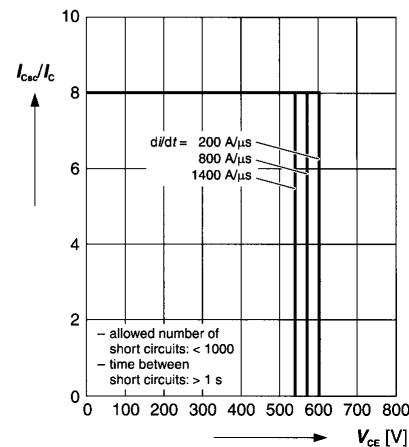
parameter: $V_{GE} = 15 V$



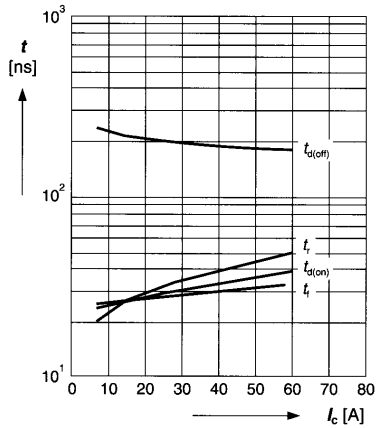
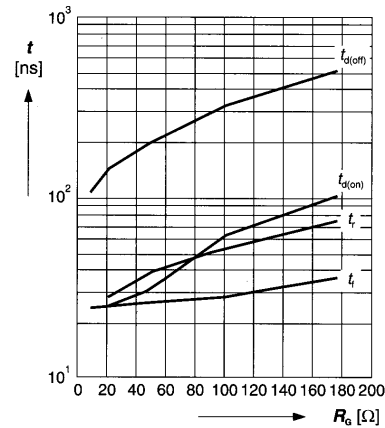
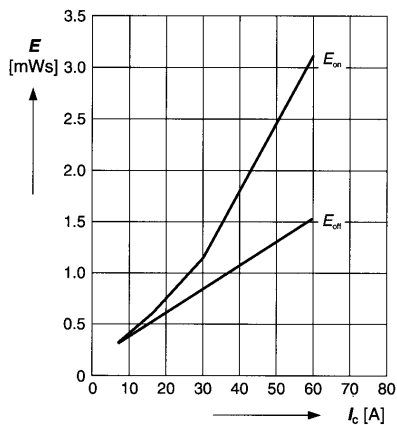
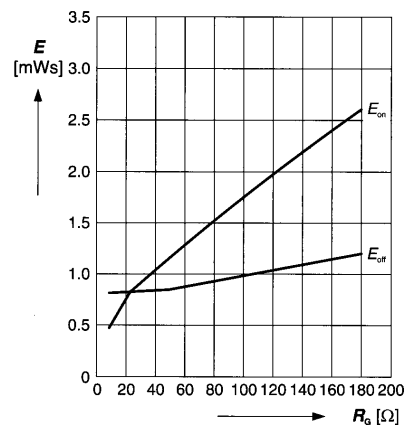
Short circuit safe operating area

$$I_{C\text{ sc}} = f(V_{CE}), T_j = 150^\circ C$$

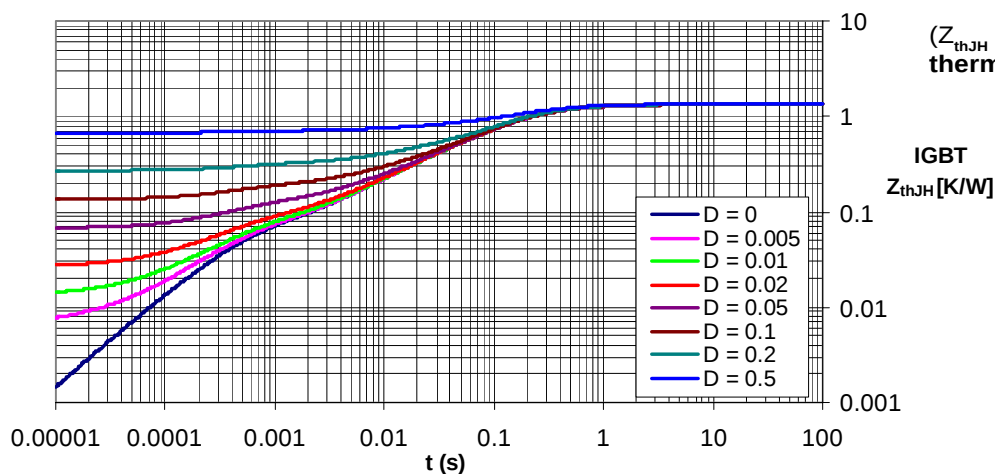
parameter: $V_{GE} = \pm 15 V$; $t_{sc} \leq 10 \mu s$; $L < 50 nH$



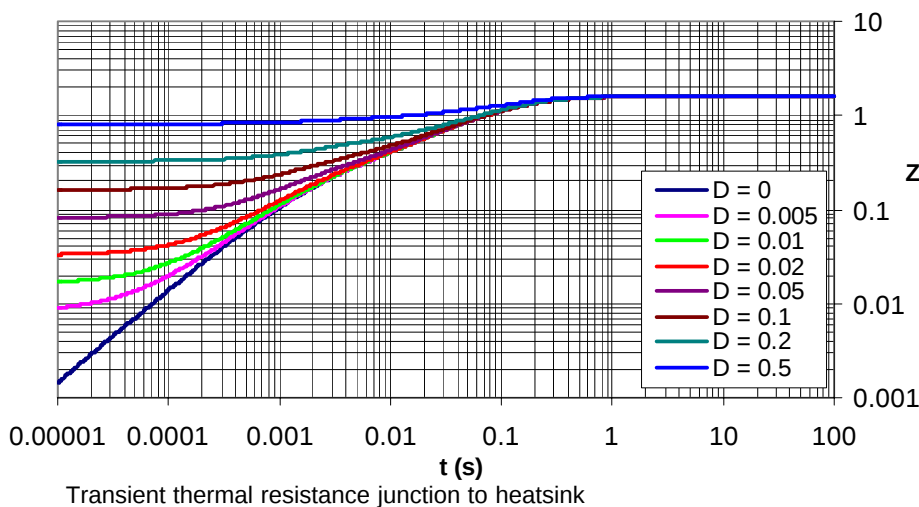
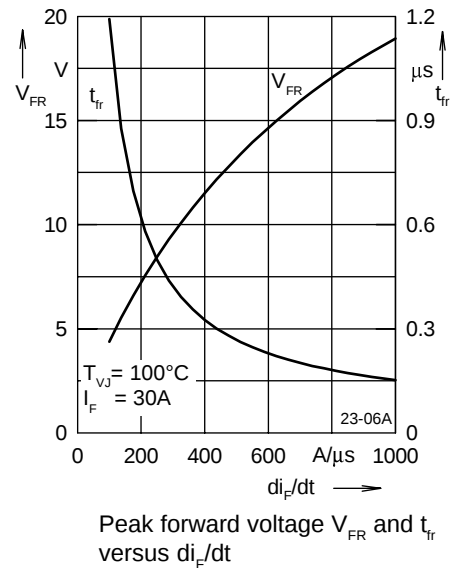
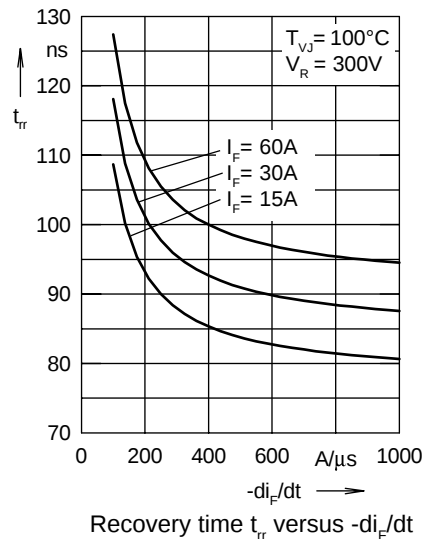
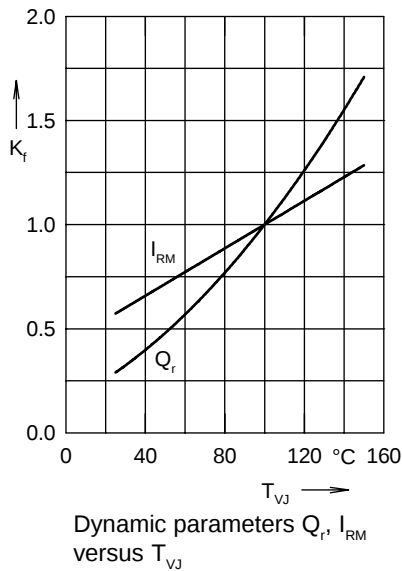
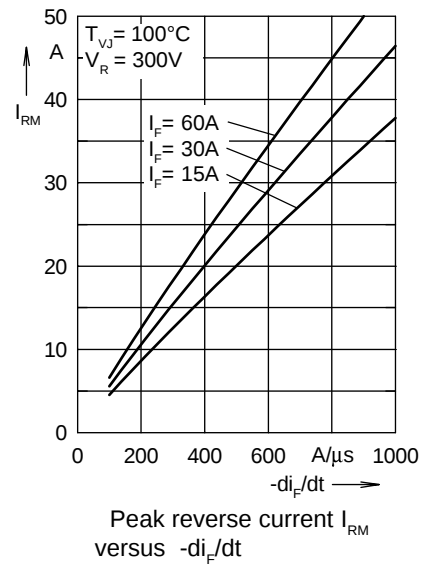
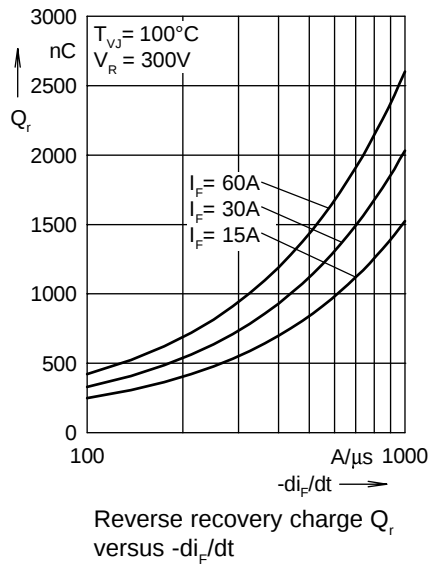
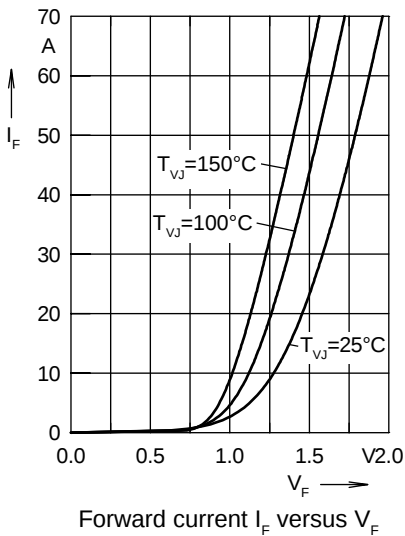
Output Inverter T1 - T6

Typ. switching time $t = f(I_C)$, inductive load, $T_J = 125^\circ\text{C}$ parameter: $V_{CE} = 300\text{ V}$; $V_{GE} = \pm 15\text{ V}$; $R_G = 33\ \Omega$ **Typ. switching time** $t = f(R_G)$, inductive load, $T_J = 125^\circ\text{C}$ parameter: $V_{CE} = 300\text{ V}$; $V_{GE} = \pm 15\text{ V}$; $I_C = 30\text{ A}$ **Typ. switching losses** $E = f(I_C)$, inductive load, $T_J = 125^\circ\text{C}$ parameter: $V_{CE} = 300\text{ V}$; $V_{GE} = \pm 15\text{ V}$; $R_G = 33\ \Omega$ **Typ. switching losses** $E = f(R_G)$, inductive load, $T_J = 125^\circ\text{C}$ parameter: $V_{CE} = 300\text{ V}$; $V_{GE} = \pm 15\text{ V}$; $I_C = 30\text{ A}$ 

Transient thermal resistance junction to heatsink

 $(Z_{thJH}$ is measured using 50 μm thermal grease)IGBT
 Z_{thJH} [K/W]

Output Inverter D1 - D6



(Z_{thJH} is measured using 50 μm thermal grease)

FRED
 $Z_{thJH} [\text{K/W}]$